NSN 5961-00-941-1923

Semiconductor Device Set - Page 1 of 2



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Inclosure Material:
Metal all transistor
Overall Length:
0.170 inches all transistor and 0.210 inches all transistor
Terminal Length:
0.500 inches all transistor
Overall Diameter:
0.209 inches all transistor and 0.230 inches all transistor
Function For Which Designed:
Chopper
Internal Configuration:
Junction contact all transistor
Internal Junction Configuration:
Pnp all transistor
Component Function Relationship:
Matched
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal all transistor
Terminal Circle Diameter:
0.100 inches all transistor
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
-30.0 breakdown voltage, collector-to-base, emitter open all transistor and -30.0 breakdown voltage, collector-to-emitter, base open all
transistor and -30.0 breakdown voltage, emitter-to-base, collector open all transistor
Current Rating Per Characteristic:
-50.00 milliamperes source cutoff current all transistor
Power Rating Per Characteristic:
150.0 milliwatts small-signal input power, common-collector preset all transistor
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction all transistor
Terminal Type And Quantity:
3 uninsulated wire lead all transistor
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

No

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Semiconductor Device Set - Page 2 of 2



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